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August 2006

FDJ1028N
N-Channel 2.5 Vgs Specified PowerTrench® MOSFET

Features

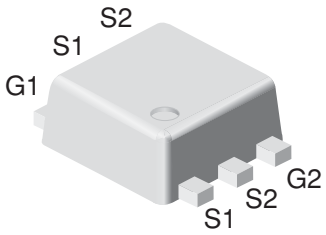
- 3.2 A, 20 V. $R_{DS(ON)}$ = 90 mΩ @ V_{GS} = 4.5 V
  $R_{DS(ON)}$ = 130 mΩ @ V_{GS} = 2.5 V
- Low gate charge
- High performance trench technology for extremely low $R_{DS(ON)}$
- FLMP SC75 package: Enhanced thermal performance in industry-standard package size

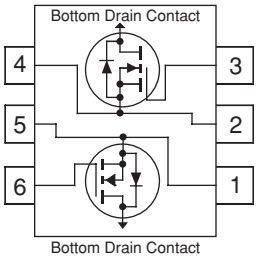
Applications

- Battery management

General Description

This dual N-Channel 2.5V specified MOSFET uses Fairchild's advanced low voltage PowerTrench process. Packaged in FLMP SC75, the $R_{DS(ON)}$ and thermal properties of the device are optimized for battery power management applications.





Absolute Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{DSS}	Drain-Source Voltage	20	V
V_{GSS}	Gate-Source Voltage	±12	V
I_D	Drain Current – Continuous (Note 1a)	3.2	A
	– Pulsed	12	
P_D	Power Dissipation for single Operation (Note 1a)	1.5	W
T_J, T_{STG}	Operating and Storage Junction Temperature Range	–55 to +150	°C
Thermal Characteristics			
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (Note 1a)	80	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	5	

Packge Marking and Ordering Information

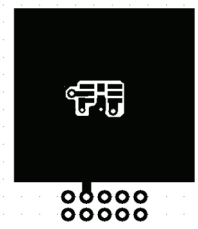
Device Marking	Device	Reel Size	Tape width	Quantity
.F	FDJ1028N	7"	8mm	3000 units

Electrical Characteristics T_A = 25°C unless otherwise noted

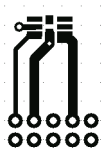
Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
Off Characteristics						
BV_{DSS}	Drain–Source Breakdown Voltage	V_{GS} = 0 V, I_D = 250 μA	20			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = 250 μA, Referenced to 25°C		13		mV/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 16 V, V_{GS} = 0 V			1	μA
I_{GSS}	Gate–Body Leakage	V_{GS} = ±12 V, V_{DS} = 0 V			±100	nA
On Characteristics (Note 2)						
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS} = V_{GS}, I_D = 250 μA	0.6	1.0	1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	I_D = 250 μA, Referenced to 25°C		–3		mV/°C
$R_{DS(on)}$	Static Drain–Source On–Resistance	V_{GS} = 4.5 V, I_D = 3.2 A V_{GS} = 2.5 V, I_D = 2.7 A V_{GS} = 4.5 V, I_D = 3.2A, T_J = 125°C		70 100 83	90 130 132	mΩ
g_{FS}	Forward Transconductance	V_{DS} = 5 V, I_D = 3.2 A		7.5		S
Dynamic Characteristics						
C_{iss}	Input Capacitance	V_{DS} = 10 V, V_{GS} = 0 V, f = 1.0 MHz		200		pF
C_{oss}	Output Capacitance			50		pF
C_{rss}	Reverse Transfer Capacitance			30		pF
R_G	Gate Resistance	f = 1.0 MHz		3		Ω
Switching Characteristics (Note 2)						
$t_{d(on)}$	Turn–On Delay Time	V_{DD} = 10 V, I_D = 1 A, V_{GS} = 4.5 V, R_{GEN} = 6 Ω		7	14	ns
t_r	Turn–On Rise Time			8	16	ns
$t_{d(off)}$	Turn–Off Delay Time			11	20	ns
t_f	Turn–Off Fall Time			2	4	ns
Q_g	Total Gate Charge	V_{DS} = 10 V, I_D = 3.2 A, V_{GS} = 4.5 V		2	3	nC
Q_{gs}	Gate–Source Charge			0.4		nC
Q_{gd}	Gate–Drain Charge			1.0		nC
Drain–Source Diode Characteristics and Maximum Ratings						
I_S	Maximum Continuous Drain–Source Diode Forward Current				1.25	A
V_{SD}	Drain–Source Diode Forward Voltage	V_{GS} = 0 V, I_S = 1.25 A (Note 2)		0.8	1.2	V
t_{rr}	Diode Reverse Recovery Time	I_F = 3.2 A, d_{iF}/d_t = 100 A/μs		11		nS
Q_{rr}	Diode Reverse Recovery Charge			2.5		nC

Notes:

1. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.



a) 80°C/W when mounted on a $1in^2$ pad of 2 oz copper (Single Operation).



b) 140°C/W when mounted on a minimum pad of 2 oz copper (Single Operation).

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300μs, Duty Cycle < 2.0%

Typical Characteristics

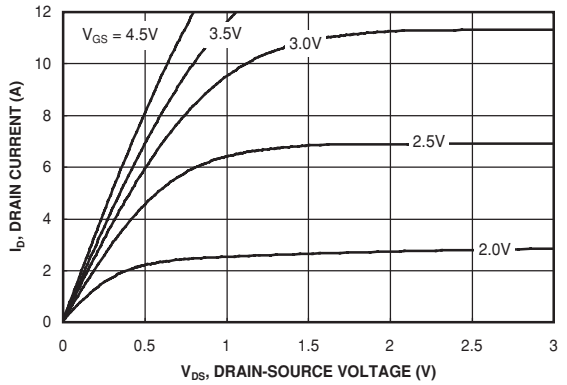


Figure 1. On-Region Characteristics.

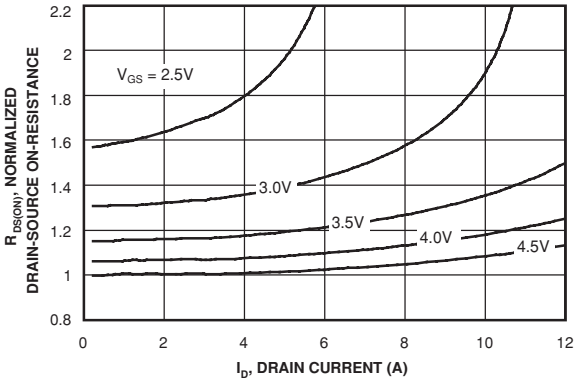


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

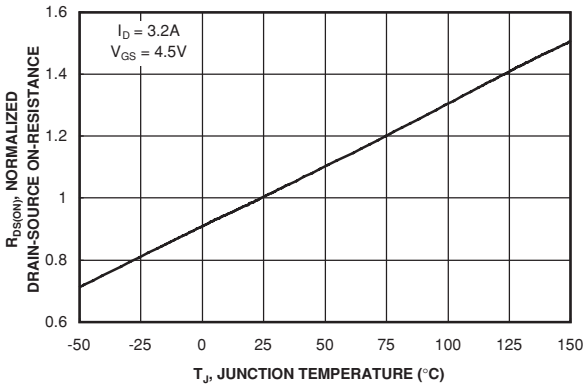


Figure 3. On-Resistance Variation with Temperature.

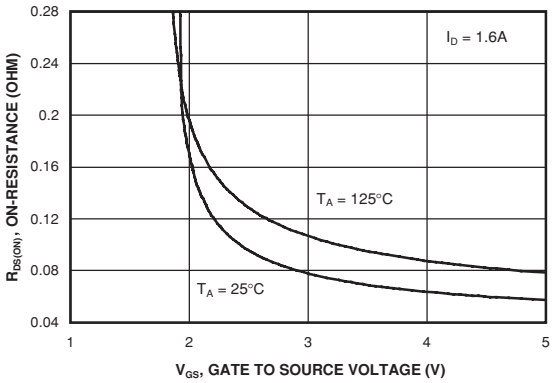


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

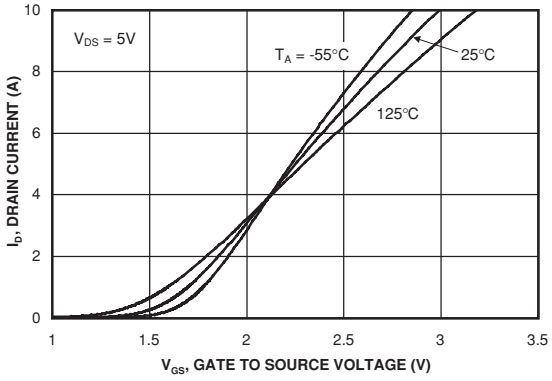


Figure 5. Transfer Characteristics.

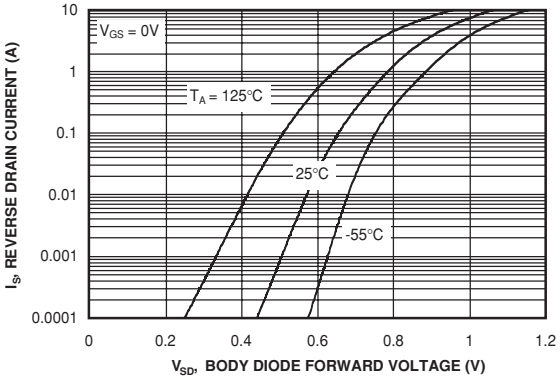


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

Typical Characteristics

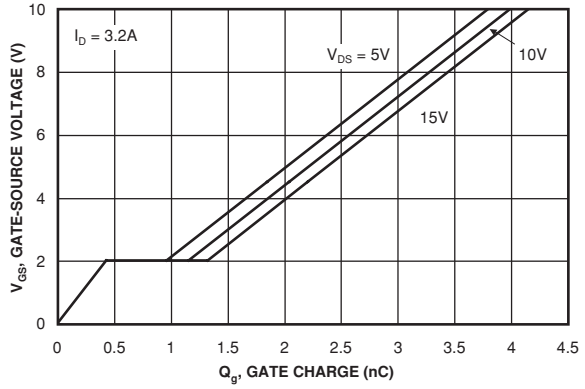


Figure 7. Gate Charge Characteristics.

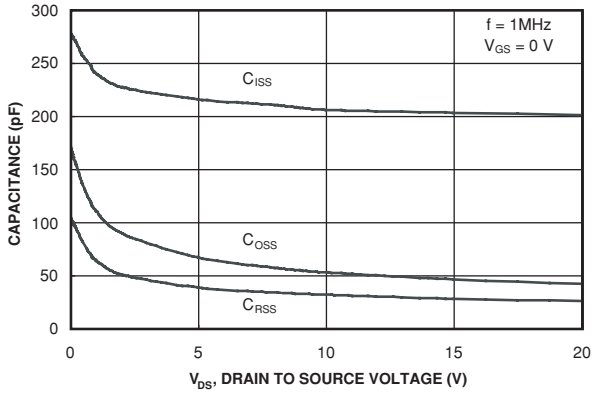


Figure 8. Capacitance Characteristics.

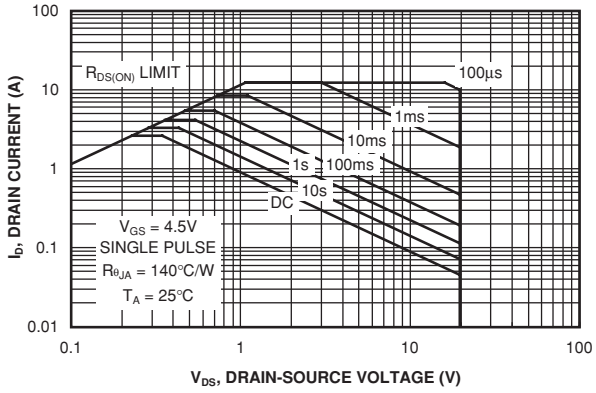


Figure 9. Maximum Safe Operating Area.

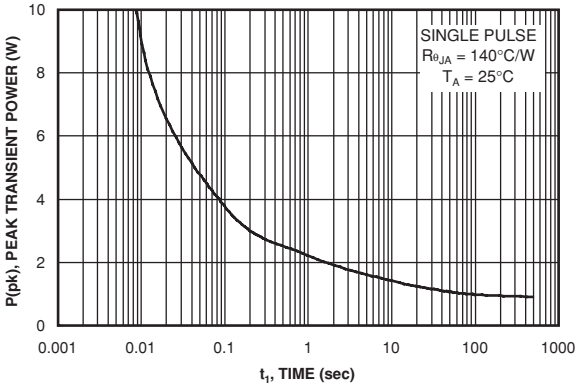


Figure 10. Single Pulse Maximum Power Dissipation.

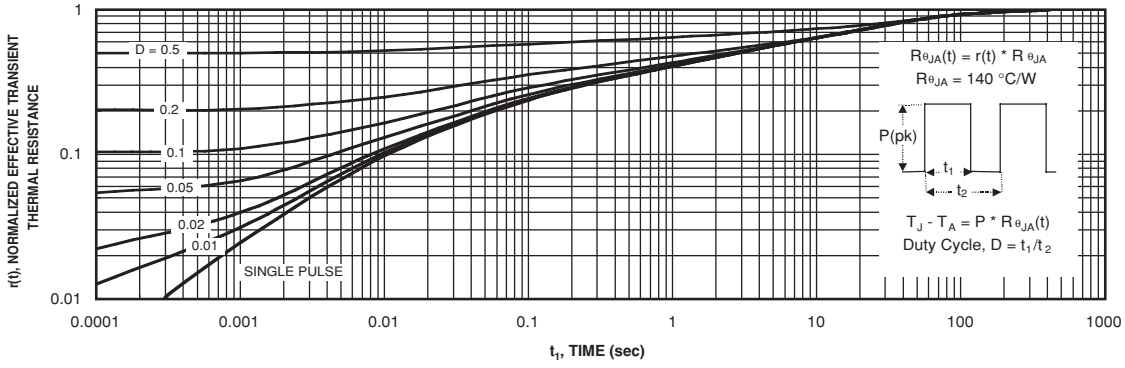
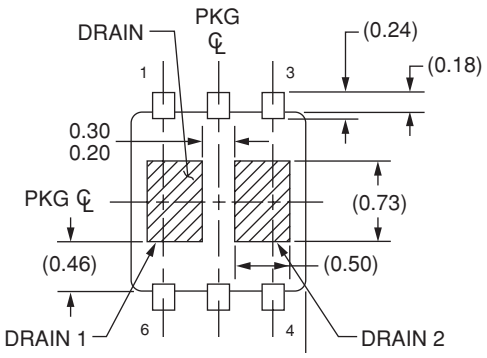


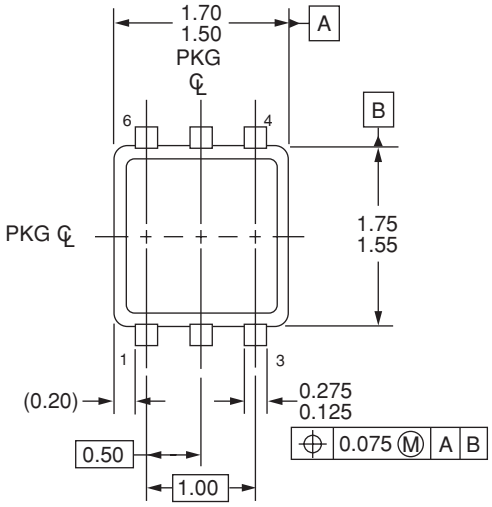
Figure 11. Transient Thermal Response Curve.

Thermal characterization performed using the conditions described in Note 1b.
Transient thermal response will change depending on the circuit board design.

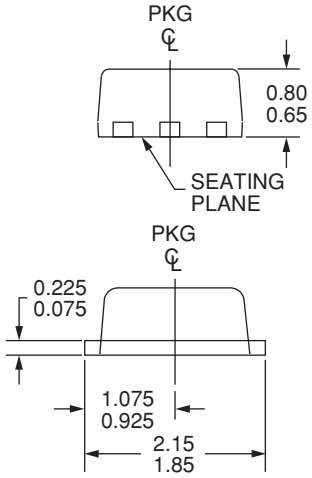
Dimensional Outline and Pad Layout

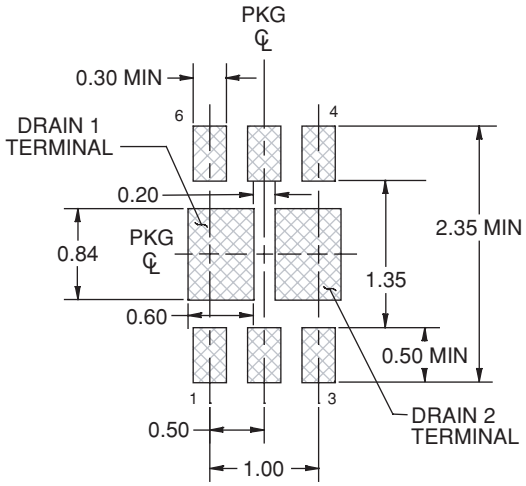


Bottom View



Top View





Recommended Landing Pattern

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